

NTHD3101FT1G

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Application

ONSEMI

Data Sheet

Power MOSFET and Schottky Diode, MOSFET - 20V - 4.4A P-Channel w/4.1A Schottky

Manufacturers	ON Semiconductor, LLC	
Package/Case	ChipFET-8	
Product Type	Transistors	
RoHS	Rohs	\$ \$ \$
Lifecycle		Images are for reference only

Please submit RFQ for NTHD3101FT1G or <u>Email to us: sales@ovaga.com</u> We will contact you in 12 hours.

General Description

Power MOSFET -20V -4.4A $80m\Omega$ P-Channel ChipFETTM4.1 A Schottky Barrier Diode

Features

Leadless SMD Package Featuring a MOSFET and Schottky Diode

40% Smaller than TSOP-6 Package

Leadless SMD Package Provides Great Thermal Characteristics

Independent Pinout to each Device to ease Circuit Design

Trench P-Channel for Low On Resistance

Ulta Low VF Schottky

Related Products



NTR4003NT3G ON Semiconductor, LLC SOT-23



<u>NTD2955G</u>

ON Semiconductor, LLC TO-252



NTZD3155CT2G

ON Semiconductor, LLC SOT-563-6



<u>NTS2101PT1G</u>

ON Semiconductor, LLC SOT-323



<u>NTR5103NT1G</u>

ON Semiconductor, LLC SOT-23

<u>NTHD4102PT1G</u>

ON Semiconductor, LLC ChipFET-8



NTMFS4C10NT1G

ON Semiconductor, LLC SO-8FL

NTH4L020N120SC1

ON Semiconductor, LLC TO-247